



DMNH6042SPS

PowerDI5060-8

Product Summary

BV _{DSS}	Rds(on) Max	I _D Max Tc = +25°C
60V	50mΩ @ V _{GS} = 10V	24A
000	65mΩ @ V _{GS} = 4.5V	21A

Description and Applications

This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) yet maintain superior switching performance, making it ideal for high-efficiency power-management applications.

- Engine management systems
- Body control electronics
- DC-DC converters

Site 1:

Features and Benefits

- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching Ensures More Reliable and Robust End Application

60V 175°C N-CHANNEL ENHANCEMENT MODE MOSFET

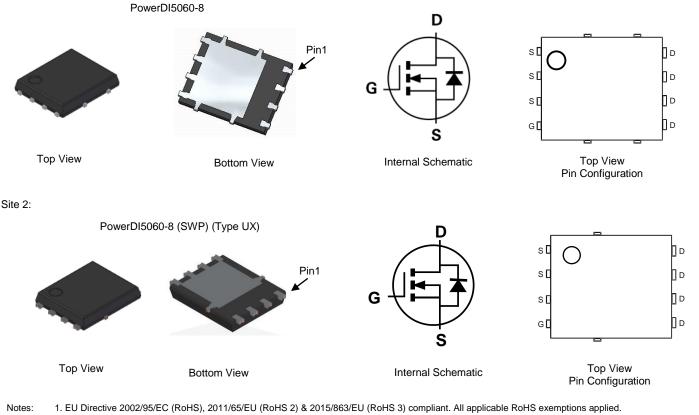
- Low R_{DS(ON)} Minimizes Power Losses
- Low Qg Minimizes Switching Losses
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

https://www.diodes.com/quality/product-definitions/

 An automotive-compliant part is available under separate datasheet (<u>DMNH6042SPSQ</u>)

Mechanical Data

- Package: PowerDI[®]5060-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.097 grams (Approximate)



2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

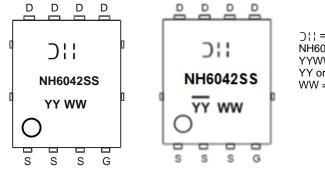


Ordering Information (Note 4)

Part Number	Deskars	Packing		
Part Number	Package	Qty.	Carrier	
DMNH6042SPS-13	PowerDI5060-8	2,500	Tape & Reel	
DMNH6042SPS-13	PowerDI5060-8 (SWP) (Type UX)	2,500	Tape & Reel	

Note: 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



);; = Manufacturer's Marking NH6042SS = Product Type Marking Code YYWW = Date Code Marking YY or \overrightarrow{YY} = Year (ex: 23 = 2023) WW = Week (01 to 53)

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	V _{DSS}	60	V		
Gate-Source Voltage	Vgss	±20	V		
Continuous Drain Current (Note 7) V_{GS} = 10V	Steady State	T _C = +25°C T _C = +100°C	ID	24 17	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%		ldм	35	A	
Maximum Continuous Body Diode Forward Current	ls	24	A		
Avalanche Current (Note 8) L = 10mH			las	3.5	A
Avalanche Energy (Note 8) L = 10mH			E _{AS}	65	mJ

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)		PD	1.5	W
Thermal Desistance, lunction to Archient (Note 5)	Steady state		98	°C/W
Thermal Resistance, Junction to Ambient (Note 5)	t<10s	RθJA	54	
Total Power Dissipation (Note 6)		PD	2.9	W
Thermal Desistance Junction to Ambient (Note 6)	Steady state	R	51	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	t<10s	RθJA	26	
Thermal Resistance, Junction to Case (Note 7)		R _{θJC}	3.5	
Operating and Storage Temperature Range		TJ, TSTG	-55 to +175	°C

Notes: 5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.

6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.

7. Thermal resistance from junction to soldering point (on the exposed drain pad).

8. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep T_J = +25°C.



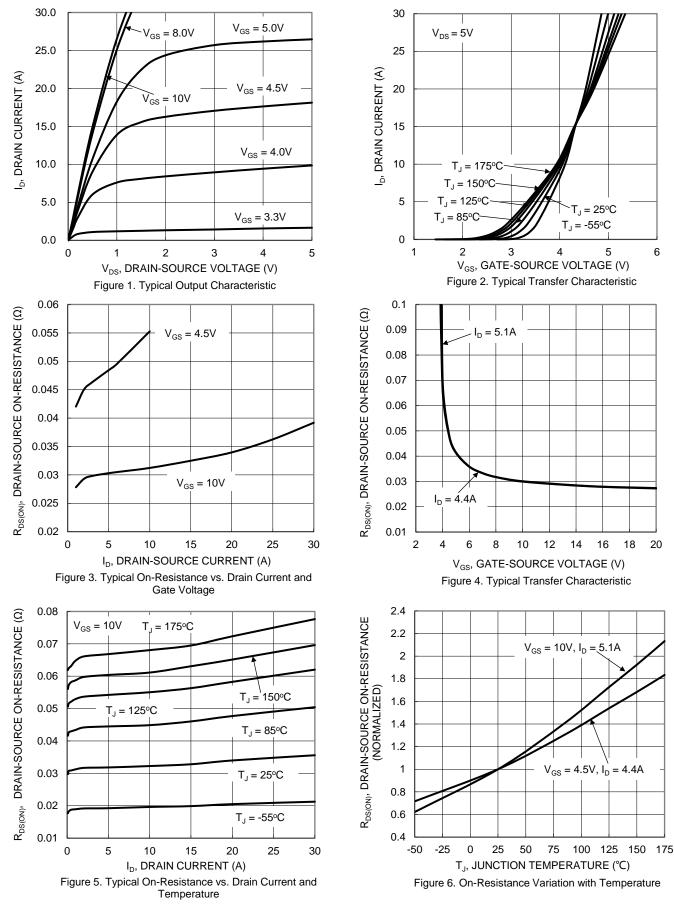
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

						-	
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 9)							
Drain-Source Breakdown Voltage	BV _{DSS}	60	_	_	V	$V_{GS} = 0V, I_D = 250 \mu A$	
Zero Gate Voltage Drain Current T _J = +25°C	IDSS	—	_	1	μA	$V_{DS} = 60V, V_{GS} = 0V$	
Gate-Source Leakage	lgss	—	—	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 9)							
Gate Threshold Voltage	VGS(TH)	1.0		3.0	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	
Static Drain-Source On-Resistance	Descent	—	34	50	mΩ	$V_{GS} = 10V, I_D = 5.1A$	
Static Dialit-Source Off-Resistance	RDS(ON)	—	45	65	11122	$V_{GS} = 4.5V, I_D = 4.4A$	
Diode Forward Voltage	V _{SD}	—	0.8	1.2	V	$V_{GS} = 0V, I_{S} = 2.6A$	
DYNAMIC CHARACTERISTICS (Note 10)							
Input Capacitance	Ciss	—	584		pF		
Output Capacitance	Coss	—	83	_	pF	Vps = 25V, Vgs = 0V, f = 1.0MHz	
Reverse Transfer Capacitance	Crss	—	24	—	pF		
Gate Resistance	Rg	—	3.8	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$	
Total Gate Charge (V _{GS} = 4.5V)	Qg	_	4.2	_	nC		
Total Gate Charge (V _{GS} = 10V)	Qg	—	8.8	—	nC	Vps = 44V. lp = 5.2A	
Gate-Source Charge	Qgs	_	1.8	—	nC	$v_{DS} = 44v, I_D = 5.2A$	
Gate-Drain Charge	Q _{gd}	—	1.8	—	nC		
Turn-On Delay Time	t _{D(ON)}	_	3.4	_	ns		
Turn-On Rise Time	tR	_	1.9	_	ns	Vgs = 10V, Vds = 30V,	
Turn-Off Delay Time	tD(OFF)	_	10.1		ns	R _G = 6Ω, I _D = 1A	
Turn-Off Fall Time	tF	_	4.5		ns		
Body Diode Reverse Recovery Time	trr	_	12.9	_	ns	IF = 2.6A, di/dt = 100A/µs	
Body Diode Reverse Recovery Charge		_	5.4		nC	I _F = 2.6A, di/dt = 100A/µs	

Notes: 9. Short duration pulse test used to minimize self-heating effect. 10. Guaranteed by design. Not subject to product testing.



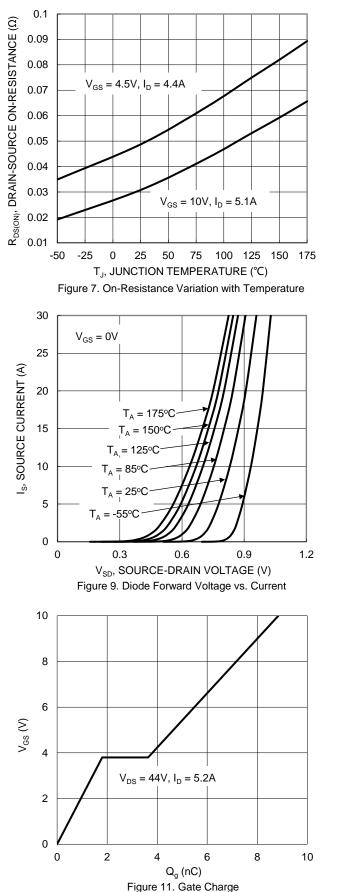
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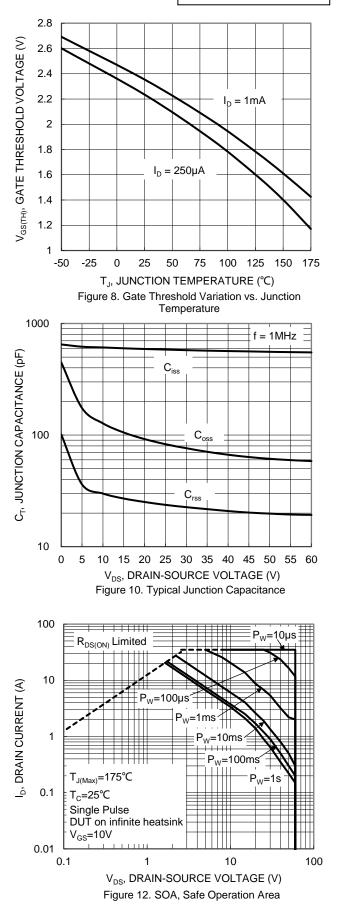


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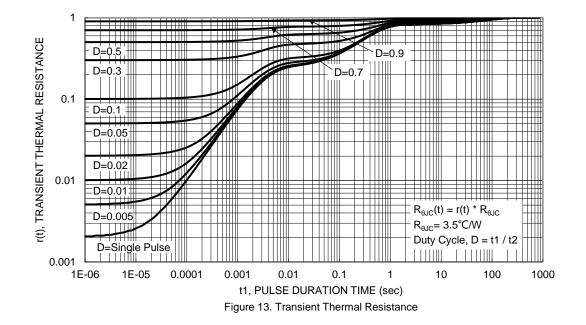


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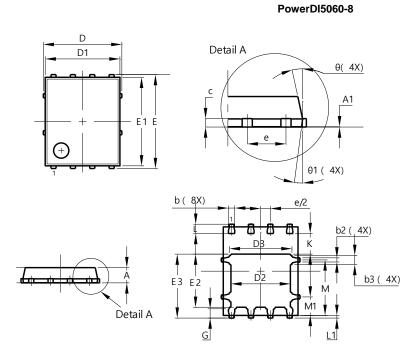




Package Outline Dimensions

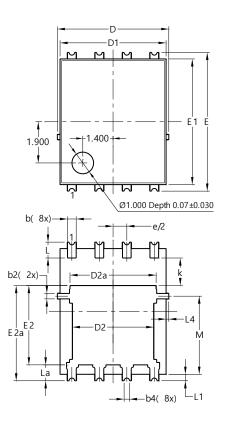
Please see http://www.diodes.com/package-outlines.html for the latest version.

Site 1:

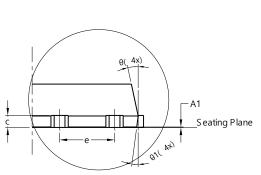


	PowerDI5060-8					
Dim	Min	Max	Тур			
Α	0.90	1.10	1.00			
A1	0.00	0.05	-			
b	0.33	0.51	0.41			
b2	0.200	0.350	0.273			
b3	0.40	0.80	0.60			
C	0.230	0.330	0.277			
D		5.15 BSC				
D1	4.70	5.10	4.90			
D2	3.70	4.10	3.90			
D3	3.90	4.30	4.10			
ш	(6.15 BSC				
E1	5.60	6.00	5.80			
E2	3.28	3.68	3.48			
E3	3.99	4.39	4.19			
е		1.27 BSC	;			
G	0.51	0.71	0.61			
ĸ	0.51	-	-			
L	0.51	0.71	0.61			
L1	0.100	0.200	0.175			
М	3.235	4.035	3.635			
M1	1.00	1.40	1.21			
Θ	10°	12°	11°			
Θ1	6°	8°	7°			
All Dimensions in mm						

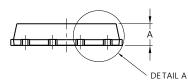
Site 2:



PowerDI5060-8/SWP (Type UX)



DETAIL A



PowerDI5060-8/SWP (Type UX)				
Dim	Min Max Typ			
Α	0.90	1.10	1.00	
A1	0	0.05		
b	0.30	0.50	0.41	
b2	0.20	0.35	0.25	
b4	().25REF	-	
С	0.230	0.330	0.277	
D	5	.15 BS0	2	
D1	4.70	5.10	4.90	
D2	3.56	3.96	3.76	
D2a	3.78	4.18	3.98	
E	6	.40 BS0	<u> </u>	
E1	5.60	6.00	5.80	
E2	3.46	3.86	3.66	
E2a	4.195	4.595	4.395	
е	1	1.27BSC)	
k	1.05			
L	0.635	0.835	0.735	
La	0.635	0.835	0.735	
L1	0.200	0.400	0.300	
L1a	-	.050RE		
L4	0.025	0.225	0.125	
Μ	3.205	4.005	3.605	
θ	10°	12°	11°	
θ1	6°	8°	7°	
All	All Dimensions in mm			

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Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

Site 1:

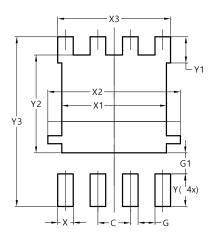
Y^{7} Y^{7

Dimensions	Value (in mm)		
С	1.270		
G	0.660		
G1	0.820		
Х	0.610		
X1	4.100		
X2	0.755		
X3	4.420		
X4	5.610		
Y	1.270		
Y1	0.600		
Y2	1.020		
Y3	0.295		
Y4	1.825		
Y5	3.810		
Y6	0.180		
Y7	6.610		

Site 2:

PowerDI5060-8/SWP (Type UX)

PowerDI5060-8



Dimensions	Value		
Dimensions	(in mm)		
С	1.270		
G	0.660		
G1	0.820		
Х	0.610		
X1	4.100		
X2	5.190		
X3	4.420		
Y	1.270		
Y1	1.020		
Y2	3.810		
Y3	6.610		



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